NSN 5962-01-293-7703

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.935 inches and 0.970 inches

Body Width:

Between 0.290 inches and 0.320 inches

Body Height:

Between 0.080 inches and 0.205 inches

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and programmable and positive outputs and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Pal

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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